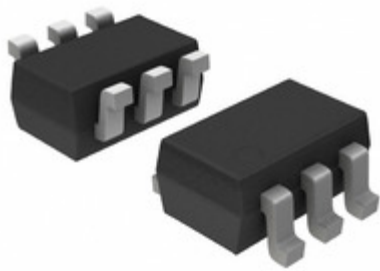









	NTJD4001NT1G	
	Hersteller-Teilenummer:	NTJD4001NT1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET 2N-CH 30V 0.25A SOT-363
<p>Image may be representation. See specs for product details.</p>	Datenblätter:	 NTJD4001NT1G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 454736 pcs Stock Available.
	Lieferrn von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	NTJD4001NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 30V 0.25A SOT-363
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	454736 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	272mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-88/SC70-6/SOT-363
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	250mA
Rds On (Max) @ Id, Vgs	1.5 Ohm @ 10mA, 4V
VGS (th) (Max) @ Id	1.5V @ 100µA
Gate Charge (Qg) (Max) @ Vgs	1.3nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	33pF @ 5V
Verpackung	Tape & Reel (TR)













































NTJD4001NT1G ist neu im Original. Suche NTJD4001NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTJD4001NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTJD4001NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTJD3115PT1G ON NTJD3115PT1G ON</p>	 <p>NTJD2152PT4G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>	 <p>NTJD4105CT1 ON ON SOT363</p>	 <p>NTJD3158CT1G O NTJD3158CT1G O</p>
 <p>NTJD3158CT2G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V SC88-6</p>	 <p>NTJD4001NT1 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 0.25A SOT363</p>	 <p>NTJD4105CT2 AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V/8V SOT-363</p>	 <p>NTJD4001NT2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 0.25A SOT363</p>

heiße Teile

Mehr

 08051A331GAT2A	 08051C101KAT2A	 AU1PG-M3/84A	 C2520C-R68J-RA	 DF200AA040
 DTA143ES	 EL8302ES	 FPD15-3.4-48	 GQM2195C2E9R0CB12D	 HD151007FPDEL
 IPD30N03S4L-14	 LM90C1MM	 LP5951MG-1.5	 LTC1732EMS-4	 M30620MCN-119FP#U0
 MAX6503UKN035+T	 MMBT3906T	 MUR20020CT	 NTE4151PT1G	 NTJD1155LT1G
 NTJD2152PT1	 NTJD2152PT1G	 NTJD3115PT1G	 NTJD3158CT1G	 NTJD3158CT2G
 NTJD4001NT2G	 NTJD4105CT1G	 NTJD4105CT2G	 NTJD4152PT1	 NTJD4152PT1G
 NTJD4158CT1G	 NTJD4158CT2G	 NTJD4401NT1	 NTJD4401NT1G	 NTJD4401NT2
 NTJD5121NT1G	 NTJD5121NT2G	 NTJS3151PT1G	 NTJS3157NT1G	 NTJS4151PT1G
 NTJS4160NT1G	 NTJS4405NT1G	 NTJS4405NT4G	 NTJS4405UT1	 NTSA0502GZ113
 SP1481EEN	 SQCSVA100JAT1A	 V48C12C150A3	 VLF403212MT-100M	 WDH0512H-2W

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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